

Fax-on-Demand: 86-22-24207687 / 25-471-1126

Tel-on-Demand: 86-22-24207688 / 25-471-1136

Before ordering check with
factory for most current data

672-1175M

RF & MICROWAVE TRANSISTORS
AVIONICS APPLICATIONS

Features

1025 – 1150 MHz

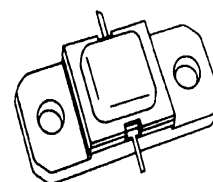
50 VOLTS

INTERNAL INPUT/OUTPUT MATCHING

$P_{OUT} = 175$ WATTS

$G_P = 7.7$ dB MINIMUM

COMMON BASE CONFIGURATION

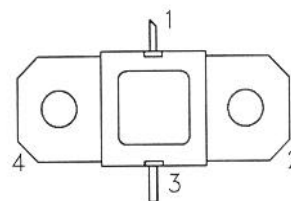


.400 x .400 2NLFL (M218)
hermetically sealed

DESCRIPTION:

The 672-1175M is a NPN bipolar transistor specifically designed for high peak pulse power applications such as DME/TACAN. This device is capable of withstanding a minimum 20:1 load VSWR at any phase angle under full rated conditions. Internal impedance matching provides consistent broadband performance.

PIN CONNECTION



1. Collector 3. Emitter
2. Base 4. Base

ABSOLUTE MAXIMUM RATINGS ($T_{case} = 25^{\circ}C$)

Symbol	Parameter	Value	Unit
P_{DISS}	Power Dissipation	400	W
I_C	Device Current	12	A
V_{CC}	Collector-Supply Voltage*	55	V
T_J	Junction Temperature	200	$^{\circ}C$
T_{STG}	Storage Temperature	-65 to +200	$^{\circ}C$

Thermal Data

$R_{TH(J-C)}$	Thermal Resistance Junction-case	0.3	$^{\circ}C/W$
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ELECTRICAL SPECIFICATIONS (Tcase = 25°C)

STATIC

Symbol	Test Conditions		Value			Unit
			Min.	Typ.	Max.	
BV_{CBO}	$I_C = 10 \text{ mA}$	$I_E = 0 \text{ mA}$	65	---	---	V
BV_{EBO}	$I_E = 1 \text{ mA}$	$I_C = 0 \text{ mA}$	3.5	---	---	V
BV_{CER}	$I_C = 15 \text{ mA}$	$R_{BE} = 10 \Omega$	65	---	---	V
I_{CES}	$V_{CE} = 50 \text{ V}$		---	---	12.5	mA
HFE	$V_{CE} = 5 \text{ V}$	$I_C = 1 \text{ A}$	15	---	120	---

DYNAMIC

Symbol	Test Conditions			Value			Unit
				Min.	Typ.	Max.	
P_{OUT}	$f = 1025 - 1150 \text{ MHz}$	$P_{IN} = 30 \text{ W}$	$V_{CC} = 50 \text{ V}$	175	---	---	W
η_C	$f = 1025 - 1150 \text{ MHz}$	$P_{IN} = 30 \text{ W}$	$V_{CC} = 50 \text{ V}$	40	---	---	%
G_P	$f = 1025 - 1150 \text{ MHz}$	$P_{IN} = 30 \text{ W}$	$V_{CC} = 50 \text{ V}$	7.7	---	---	dB
Condition	Pulse Width = 10uS Duty Cycle = 1%						

IMPEDANCE DATA

FREQ	$Z_{IN} (\Omega)$	$Z_{CL} (\Omega)$
1025 MHz	$2.3 + j5.1$	$2.4 - j4.2$
1090 MHz	$2.0 + j4.5$	$2.0 - j3.5$
1150 MHz	$2.2 + j3.3$	$2.5 - j2.5$

$V_{CC} = 50V$

$P_{IN} = 30W$

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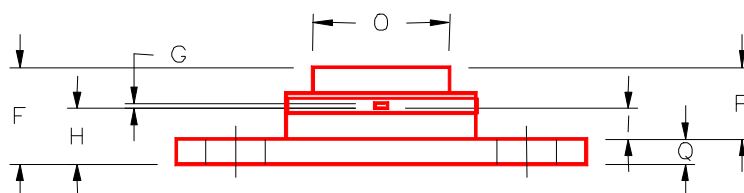
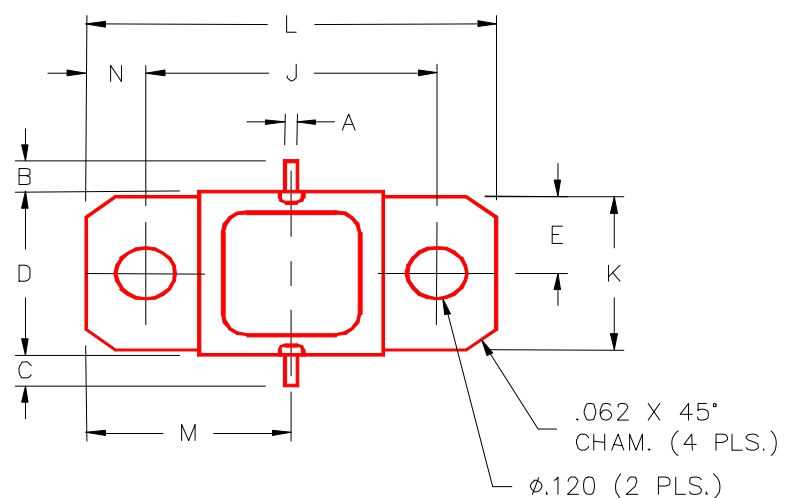
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**RF & MICROWAVE TRANSISTORS
AVIONICS APPLICATIONS**

PACKAGE MECHANICAL DATA

PACKAGE STYLE M218



	MINIMUM INCHES/MM	MAXIMUM INCHES/MM		MINIMUM INCHES/MM	MAXIMUM INCHES/MM
A	.025/0,64		J	.650/16,51	
B	.100/2,54		K	.386/9,80	
C	.100/2,54		L	.900/22,86	
D	.395/10,03	.407/10,34	M	.450/11,43	
E	.193/4,90		N	.125/3,18	
F		.230/5,84	O	.405/10,29	
G	.004/0,10	.007/0,18	P		.170/4,32
H	.118/3,00	.131/3,33	Q	.062/1,58	
I	.063/1,60				